ESH3B, ESH3C, ESH3D

Vishay General Semiconductor

Surface-Mount Ultrafast Plastic Rectifier



SMC (DO-214AB)

Cathode O Anode

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	3.0 A				
V _{RRM}	100 V, 150 V, 200 V				
t _{rr}	25 ns				
V _F at I _F	0.90 V				
T _J max.	175 °C				
Package	SMC (DO-214AB)				
Circuit configuration	Single				

FEATURES

- Glass passivated pellet chip junction
- · Ideal for automated placement
- Ultrafast recovery times for high efficiency
- Low forward voltage, low power loss
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- RoHS COMPLIANT

AUTOMOTIVE GRADE

- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converter and inverter for both, industrial and automotive.

MECHANICAL DATA

Case: SMC (DO-214AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, industrial grade Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ESH3B	ESH3C	ESH3D	UNIT	
Device marking code		EHB	EHC	EHD		
Maximum repetitive peak reverse voltage	V_{RMM}	100	150	200		
Maximum RMS voltage	V _{RMS}	70	105	140	V	
Maximum DC blocking voltage	V_{DC}	100	150	200		
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	3.0				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	125			А	
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +175			°C	

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
Maximum instantaneous forward voltage	I _F = 3 A		V _F ⁽¹⁾	0.90	V	
Maximum DC reverse current		T _A = 25 °C	1	5.0	μΑ	
at rated DC blocking voltage		T _A = 125 °C	- I _R	150		
Maximum reverse recovery time	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		t _{rr}	25		
Typical reverse recovery time	$I_F = 3 \text{ A}, V_R = 30 \text{ V},$ $dI/dt = 50 \text{ A/}\mu\text{s}, I_{rr} = 10 \% I_{RM}$	T _J = 25 °C	- t _{rr}	40	ns	
		T _J = 100 °C		55		
Typical stored charge	$I_{\rm F} = 3 \text{ A}, V_{\rm R} = 30 \text{ V},$	T _J = 25 °C	Q _{rr}	25	nC	
	$dI/dt = 50 \text{ A/}\mu\text{s}, I_{rr} = 10 \% I_{RM}$	T _J = 100 °C		60		
Typical junction capacitance	4.0 V, 1 MHz		CJ	70	pF	

Note

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ESH3B ESH3C ESH3D				
Typical thormal registance	R ₀ JA (1)	50			°C/W	
Typical thermal resistance	R ₀ JL (1)		15		C/VV	

Note

⁽¹⁾ Units mounted on PCB with 12.0 mm x 12.0 mm land areas

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ESH3D-E3/57T	0.211	57T	850	7" diameter plastic tape and reel		
ESH3D-E3/9AT	0.211	9AT	3500	13" diameter plastic tape and reel		
ESH3DHE3_A/H (1)	0.211	Н	850	7" diameter plastic tape and reel		
ESH3DHE3_A/I (1)	0.211	I	3500	13" diameter plastic tape and reel		

Note

⁽¹⁾ AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

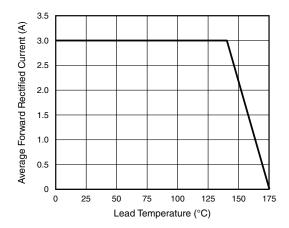


Fig. 1 - Maximum Forward Current Derating Curve

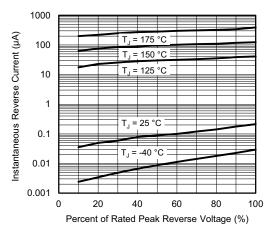


Fig. 4 - Typical Reverse Leakage Characteristics

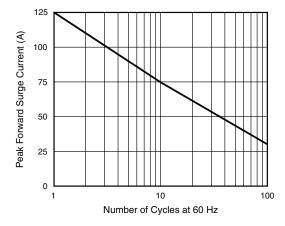


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

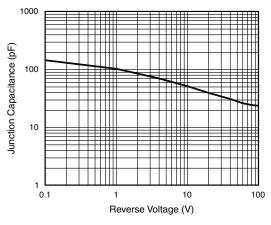


Fig. 5 - Typical Junction Capacitance

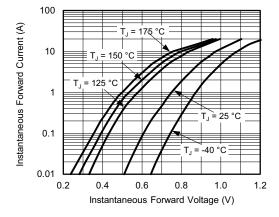


Fig. 3 - Typical Instantaneous Forward Characteristics

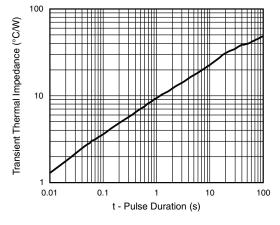


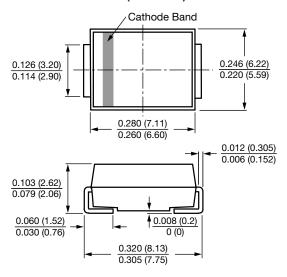
Fig. 6 - Typical Transient Thermal Impedance

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

SMC (DO-214AB)



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